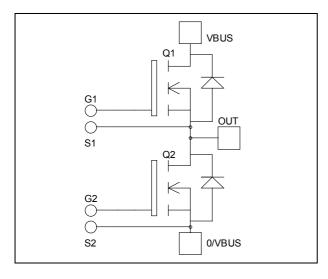
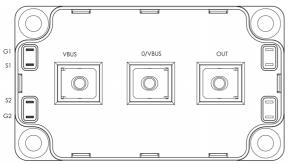


Phase leg MOSFET Power Module

 $V_{DSS} = 100V$ $R_{DSon} = 2.25m\Omega$ typ @ Tj = 25°C $I_D = 495A$ @ Tc = 25°C





Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS V[®] FREDFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Fast intrinsic diode
 - Very rugged
 - Kelvin source for easy drive
 - Very low stray inductance
 - Symmetrical design
 - M5 power connectors
 - High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		100	V
Ţ	Continuous Drain Current	$T_c = 25$ °C	495	
I_D	Continuous Drain Current	$T_c = 80$ °C	370	A
I_{DM}	Pulsed Drain current		1900	
V_{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		2.5	mΩ
P_{D}	Maximum Power Dissipation $T_c = 25^{\circ}C$		1250	W
I_{AR}	Avalanche current (repetitive and non repetitive)		100	A
E_{AR}	Repetitive Avalanche Energy		50	mJ
E_{AS}	Single Pulse Avalanche Energy		3000	1113

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$	$T_j = 25^{\circ}C$			400	4	
		$V_{GS} = 0V, V_{DS} = 80V$	$T_j = 125^{\circ}C$			2000	μА	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 200A$			2.25	2.5	mΩ	
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 10$ mA		2		4	V	
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$		·		±400	nA	

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		40		
C_{oss}	Output Capacitance	$V_{\rm DS} = 25V$		15.7		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		5.9		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		1360		
Q_{gs}	Gate – Source Charge	$V_{\text{Bus}} = 50V$		240		nC
Q_{gd}	Gate – Drain Charge	$I_D = 400A$		720		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		160		
T_{r}	Rise Time	$V_{GS} = 15V$ $V_{Bus} = 66V$		240		na
$T_{d(off)}$	Turn-off Delay Time	$I_{\rm D} = 400 A$		500		ns
T_{f}	Fall Time	$R_G = 1.25\Omega$		160		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		2.2		m I
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 400A, R_G = 1.25\Omega$		2.41		mJ
E_{on}	Turn-on Switching Energy	Inductive switching @ 125°C		2.43		Т
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 400A, R_G = 1.25\Omega$		2.56		mJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_S	Continuous Source current		$Tc = 25^{\circ}C$			495	Α
	(Body diode)		$Tc = 80^{\circ}C$			370	Λ
$ m V_{SD}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -400A$				1.3	V
dv/dt	Peak Diode Recovery					5	V/ns
t _{rr}	Reverse Recovery Time	4004	$T_j = 25$ °C			190	ns
чт	The verse receivery Time	$I_S = -400A$ $V_R = 66V$	$T_j = 125$ °C			370	115
Q _{rr}	Reverse Recovery Charge	$di_{S}/dt = 400A/\mu s$	$T_j = 25^{\circ}C$		1.6		μC
	reverse receivery charge		$T_{j} = 125^{\circ}C$		6.8		μυ

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

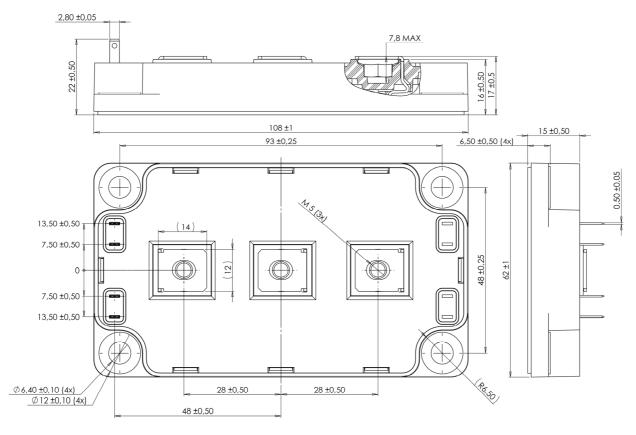
 $I_S \leq \text{- 495A} \qquad \text{di/dt} \leq 400 \text{A/} \mu \text{s} \qquad V_R \leq V_{DSS} \qquad \quad T_j \leq 150 ^{\circ} \text{C}$



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance					0.1	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150		
T_{STG}					125	°C	
$T_{\rm C}$						100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Torque		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

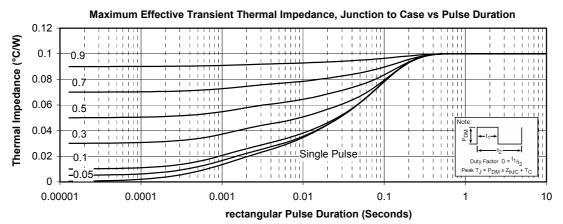
SP6 Package outline (dimensions in mm)

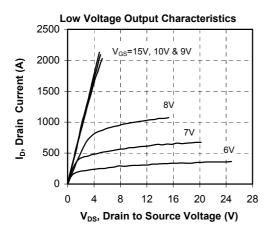


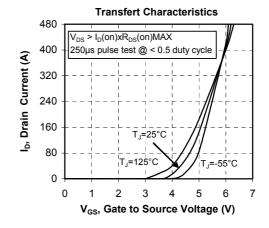
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

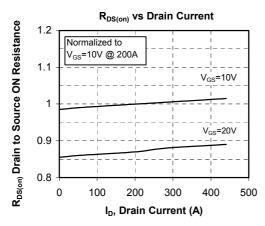


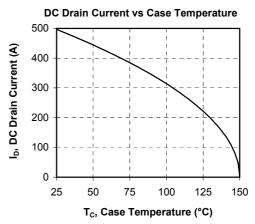
Typical Performance Curve



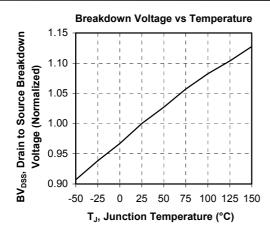


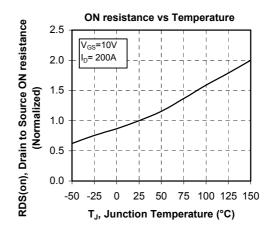


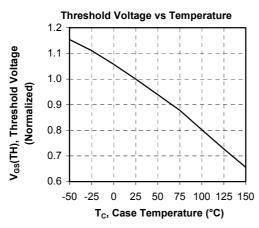


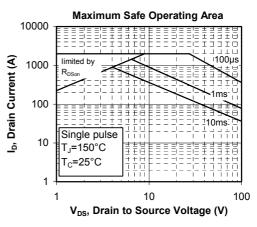


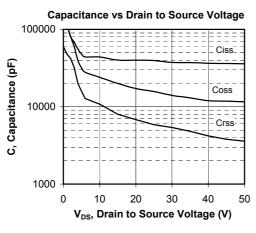


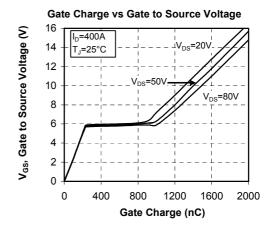




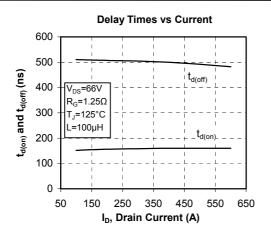


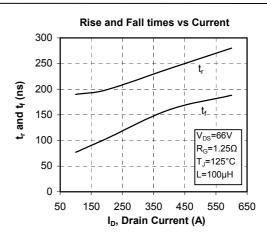


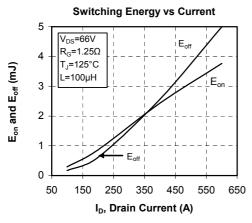


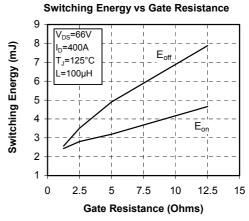


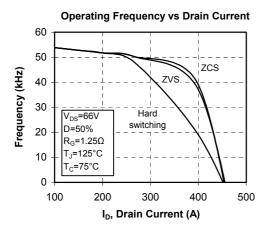


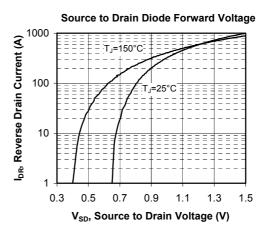














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